New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.
SPRINGFIELD, NEW JERSEY 07081
U.S.A.

TELEPHONE: (973) 376-2922
(212) 227-6005
FAX: (973) 376-8960

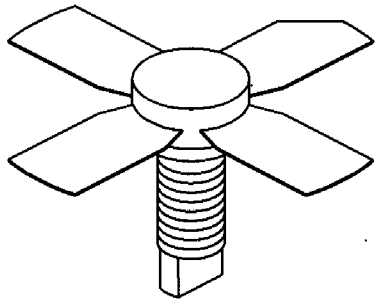
UTV040

4 Watts, 25 Volts, Class A
UHF Television - Band IV & V

GENERAL DESCRIPTION

The UTV 040 is a COMMON EMITTER transistor capable of providing 4 Watt Peak, Class A, RF Output Power over the band 470 - 860 MHz. Gold Metalization and Diffused Ballasting are used to provide high reliability and supreme ruggedness.

CASE OUTLINE
55FT, STYLE 2



ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation @ 25°C		25 Watts
Maximum Voltage and Current		
BVces	Collector to Emitter Voltage	45 Volts
BVceo	Collector to Emitter Voltage	25 Volts
BVebo	Emitter to Base Voltage	4.0 Volts
Ic	Collector Current	2.5 Amps
Maximum Temperatures		
Storage Temperature		- 65 to + 150°C
Operating Junction Temperature		+ 200°C

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Out - Pk Sync	F = 470 - 860 MHz	4.0			Watts
Pin	Power Input	Vcc = 25 Volts			0.65	Watts
Pg	Power Gain	Ic = 850 mA		9.0		dB
IMD[1]	Intermodulation Distortion	Pref = 4.0 Watts		-60		dB
$VSWR_1$	Load Mismatch Tolerance	F = 860 MHz			30:1	

LVceo	Collector to Emitter Breakdown	Ic = 20 mA	25			Volts
BVces	Collector to Base Breakdown	Ic = 20 mA	45			Volts
BVebo	Emitter to Base Breakdown	Ie = 1 mA	4.0			Volts
h_{FE}	Current Gain	Vce = 5 V, 500 mA	10	17	100	
Cob	Output Capacitance	Vcb = 25 V, F = 1 MHz	10			pF
θjc	Thermal Resistance	Tc = 25°C			7.0	°C/W

Note 1: F1=860 MHz, F2=863.5 MHz, F3=864.5 Mhz
European test method, Vision = - 8dB, Sideband= - 16dB, Sound = -7 dB